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INVESTIGATING DIFFUSION OF XENON IMPLANTED GLASSY CARBON

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Recently, there has been a renewed interest in employing glassy carbonto contain radioactive fission products. One of the fission products, Xe is significant by itself due to its high neutron absorption cross section and high production as a fission product. 200 keV Xenon (Xe) ions were implanted in the glassy carbon samples to a fluence of 1×10^{-16} Xe+ cm-2 at room temperature. The diffusion of the implanted Xenon in the glassy carbon was measured using Rutherford backscattering (RBS) after vacuum annealing. The surface topography of the samples before and after each annealing temperature was investigated using scanning electron microscopy (SEM).

Apply to be
 considered for a student
 award (Yes / No)?

Yes

Level for award
 (Hons, MSc,
 PhD, N/A)?

PhD

Main supervisor (name and email)
and his / her institution

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Would you like to
 submit a short paper
 for the Conference
 Proceedings (Yes / No)?

Yes

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